

## T493C336K010BT6420

T493 HRA, Tantalum, MnO2 Tantalum, HRA, 33 uF, 10%, 10 VDC, SMD, MnO2, Molded, DLA Drawing, B (0.1%/1000 Hrs), 300 mOhms, 2.8 mm, 2312 / 6032



Click [here](#) for the 3D model.

### General Information

Series	T493 HRA
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, DLA Drawing
RoHS	Yes
Termination	Tin
Typical Component Weight	224.2 mg

### Dimensions

L	6mm +/-0.3mm
W	3.2mm +/-0.3mm
H	2.5mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.2mm +/-0.1mm

### Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

### Specifications

Capacitance	33 uF
Tolerance	10%
Voltage DC	10 VDC (85C), 6.7 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	B (0.1%/1000 Hrs)
ESR	0.3 Ohms (100kHz 25C)
Ripple Current	606 mA (rms, 100kHz 25C)
Leakage Current	3.3 uA (5min 25°C)
Testing and Reliability	10 Cycles Surge Current Testing At -55C +/-5C And +85C +/-5C Before Weibull

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